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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

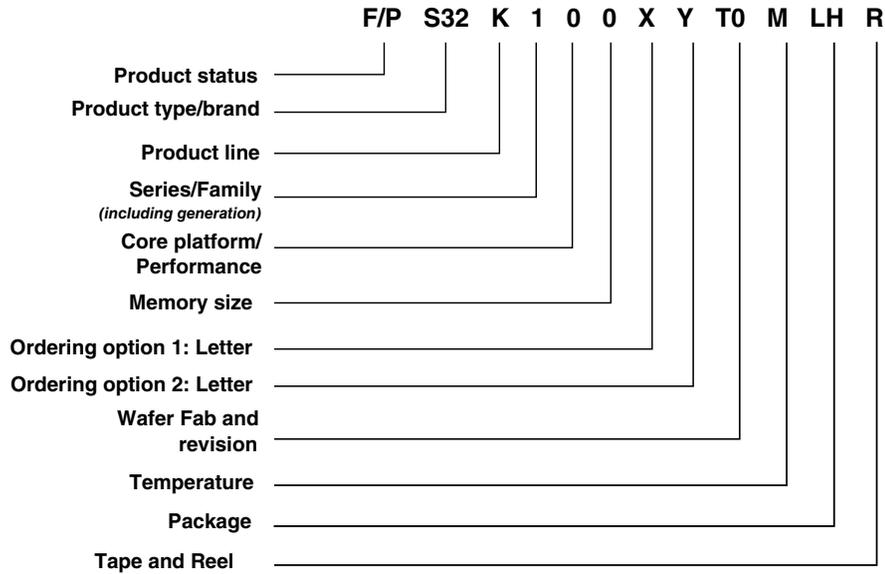
### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	ARM® Cortex®-M4F
Core Size	32-Bit Single-Core
Speed	112MHz
Connectivity	CANbus, FlexIO, I <sup>2</sup> C, LINbus, SPI, UART/USART
Peripherals	POR, PWM, WDT
Number of I/O	58
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	64K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 16x12b SAR; D/A1x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/fs32k144urt0vlht">https://www.e-xfl.com/product-detail/nxp-semiconductors/fs32k144urt0vlht</a>

- Communications interfaces
  - Up to three Low Power Universal Asynchronous Receiver/Transmitter (LPUART/LIN) modules with DMA support and low power availability
  - Up to three Low Power Serial Peripheral Interface (LPSPI) modules with DMA support and low power availability
  - Up to two Low Power Inter-Integrated Circuit (LPI2C) modules with DMA support and low power availability
  - Up to three FlexCAN modules (with optional CAN-FD support)
  - FlexIO module for emulation of communication protocols and peripherals (UART, I2C, SPI, I2S, LIN, PWM, etc).
  - Up to one 10/100Mbps Ethernet with IEEE1588 support and two Synchronous Audio Interface (SAI) modules.
- Safety and Security
  - Cryptographic Services Engine (CSEc) implements a comprehensive set of cryptographic functions as described in the SHE (Secure Hardware Extension) Functional Specification. Note: CSEc (Security) or EEPROM writes/erase will trigger error flags in HSRUN mode (112 MHz) because this use case is not allowed to execute simultaneously. The device will need to switch to RUN mode (80 MHz) to execute CSEc (Security) or EEPROM writes/erase.
  - 128-bit Unique Identification (ID) number
  - Error-Correcting Code (ECC) on flash and SRAM memories
  - System Memory Protection Unit (System MPU)
  - Cyclic Redundancy Check (CRC) module
  - Internal watchdog (WDOG)
  - External Watchdog monitor (EWM) module
- Timing and control
  - Up to eight independent 16-bit FlexTimers (FTM) modules, offering up to 64 standard channels (IC/OC/PWM)
  - One 16-bit Low Power Timer (LPTMR) with flexible wake up control
  - Two Programmable Delay Blocks (PDB) with flexible trigger system
  - One 32-bit Low Power Interrupt Timer (LPIT) with 4 channels
  - 32-bit Real Time Counter (RTC)
- Package
  - 32-pin QFN, 48-pin LQFP, 64-pin LQFP, 100-pin LQFP, 100-pin MAPBGA, 144-pin LQFP, 176-pin LQFP package options
- 16 channel DMA with up to 63 request sources using DMAMUX

## 3.2 Ordering information



**Product status**

P: Prototype  
F: Qualified

**Product type/brand**

S32: Automotive 32-bit MCU

**Product line**

K: Arm Cortex MCUs

**Series/Family**

1: 1st product series  
2: 2nd product series

**Core platform/Performance**

1: Arm Cortex M0+  
4: Arm Cortex M4F

**Memory size**

	2	4	6	8
S32K11x			128K	256K
S32K14x	256K	512K	1M	2M

**Ordering option**

X: Speed  
B: 48 MHz without DMA (S32K11x only)  
L: 48 MHz with DMA (S32K11x only)  
H: 80 MHz  
U1: 112 MHz (Not valid with M temperature/125C)

**Y: Optional feature**

R: Base feature set  
F: CAN FD, FlexIO  
A1: CAN FD, FlexIO, Security  
E: Ethernet, Serial Audio Interface (S32K148 only)  
J1: Ethernet, Serial Audio Interface, CAN FD, FlexIO, Security (S32K148 only)

**Wafer, Fab and revision**

Fx: ATMC<sup>2</sup>  
Tx: GF  
XX: Flex #<sup>2</sup>

x0: 1st revision

**Temperature**

V: -40C to 105C  
M: -40C to 125C  
W: -40C to 150C<sup>2</sup>

**Package**

Pins	LQFP	QFN	BGA
32	-	FM	-
48	LF	-	-
64	LH	-	-
100	LL	-	MH
144	LQ	-	-
176	LU	-	-

**Tape and Reel**

T: Trays/Tubes  
R: Tape and Reel

- CSEc (Security) or EEPROM writes/erase will trigger error flags in HSRUN mode (112 MHz) because this use case is not allowed to execute simultaneously. The device will need to switch to RUN mode (80 MHz) to execute CSEc (Security) or EEPROM writes/erase.
- Not supported yet
- Part numbers no longer offered as standard include:  
Ordering Option X (M:64MHz); Ordering Option Y (N: limited RAM. 16KB for K142, 48KB for K144, 96KB for K146, 192KB for K148 S: Security); Temperature (C: -40C to 85C)

**NOTE**

Not all part number combinations are available. See S32K1xx\_Orderable\_Part\_Number\_List.xlsx attached with the Datasheet for list of standard orderable parts.

**Figure 4. Ordering information**

## General

4. When input pad voltage levels are close to  $V_{DD}$  or  $V_{SS}$ , practically no current injection is possible.
5. While respecting the maximum current injection limit
6. This is the Electronic Control Unit (ECU) supply ramp rate and not directly the MCU ramp rate. Limit applies to both maximum absolute maximum ramp rate and typical operating conditions.
7. This is the MCU supply ramp rate and the ramp rate assumes that the S32K1xx HW design guidelines in AN5426 are followed. Limit applies to both maximum absolute maximum ramp rate and typical operating conditions.
8.  $T_J$  (Junction temperature)=135 °C. Assumes  $T_A$ =125 °C for RUN mode  
 $T_J$  (Junction temperature)=125 °C. Assumes  $T_A$ =105 °C for HSRUN mode
  - Assumes maximum  $\theta_{JA}$  for 2s2p board. See [Thermal characteristics](#)
9. 60 seconds lifetime; device in reset (no outputs enabled/toggling)

## 4.2 Voltage and current operating requirements

### NOTE

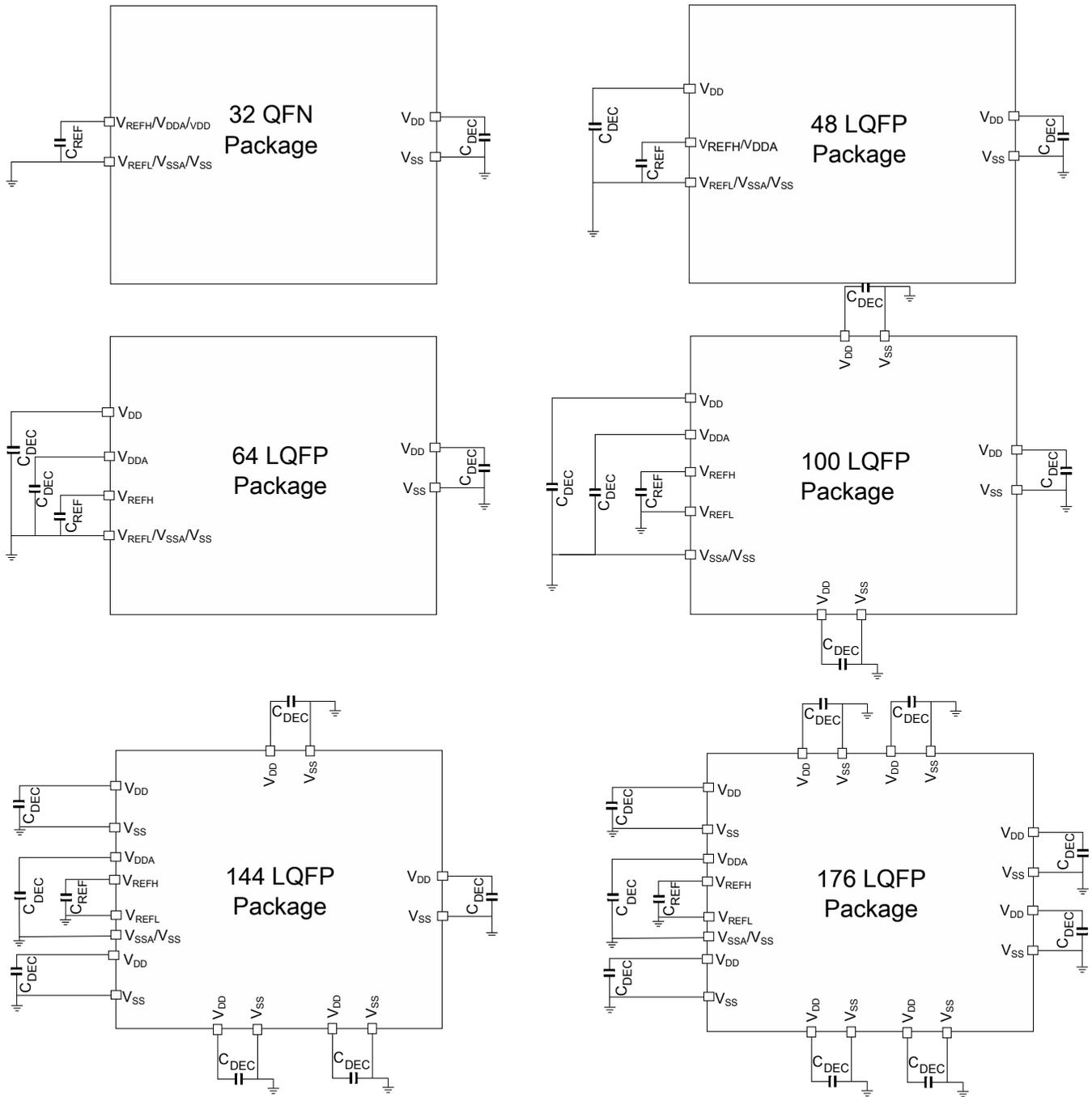
Device functionality is guaranteed up to the LVR assert level, however electrical performance of 12-bit ADC, CMP with 8-bit DAC, IO electrical characteristics, and communication modules electrical characteristics would be degraded when voltage drops below 2.7 V

**Table 2. Voltage and current operating requirements 1**

Symbol	Description	Min.	Max.	Unit	Notes
$V_{DD}^2$	Supply voltage	2.7 <sup>3</sup>	5.5	V	4
$V_{DD\_OFF}$	Voltage allowed to be developed on $V_{DD}$ pin when it is not powered from any external power supply source.	0	0.1	V	
$V_{DDA}$	Analog supply voltage	2.7	5.5	V	4
$V_{DD} - V_{DDA}$	$V_{DD}$ -to- $V_{DDA}$ differential voltage	-0.1	0.1	V	4
$V_{REFH}$	ADC reference voltage high	2.7	$V_{DDA} + 0.1$	V	5
$V_{REFL}$	ADC reference voltage low	-0.1	0.1	V	
$V_{ODPU}$	Open drain pullup voltage level	$V_{DD}$	$V_{DD}$	V	6
$I_{INJPAD\_DC\_OP}^7$	Continuous DC input current (positive / negative) that can be injected into an I/O pin	-3	+3	mA	
$I_{INJSUM\_DC\_OP}$	Continuous total DC input current that can be injected across all I/O pins such that there's no degradation in accuracy of analog modules: ADC and ACMP (See section <a href="#">Analog Modules</a> )	—	30	mA	

1. Typical conditions assumes  $V_{DD} = V_{DDA} = V_{REFH} = 5$  V, temperature = 25 °C and typical silicon process unless otherwise stated.
2. As  $V_{DD}$  varies between the minimum value and the absolute maximum value the analog characteristics of the I/O and the ADC will both change. See section [I/O parameters](#) and [ADC electrical specifications](#) respectively for details.
3. S32K148 will operate from 2.7 V when executing from internal FIRC. When the PLL is engaged S32K148 is guaranteed to operate from 2.97 V. All other S32K family devices operate from 2.7 V in all modes.
4.  $V_{DD}$  and  $V_{DDA}$  must be shorted to a common source on PCB. The differential voltage between  $V_{DD}$  and  $V_{DDA}$  is for RF-AC only. Appropriate decoupling capacitors to be used to filter noise on the supplies. See application note [AN5032](#) for reference supply design for SAR ADC.

## 4.4 Power and ground pins



NOTE:  $V_{DD}$  and  $V_{DDA}$  must be shorted to a common source on PCB

**Figure 5. Pinout decoupling**

**Table 8. VLPS additional use-case power consumption at typical conditions**

Use-case	Description	Temp.	Device						Unit
			S32K116	S32K118	S32K142	S32K144	S32K146	S32K148	
VLPS and RTC	<ul style="list-style-type: none"> <li>• Clock source: LPO or RTC_CLKIN</li> </ul>	25	TBD	TBD	30	30	30	40	μA
		85	TBD	TBD	110	170	180	240	μA
		105	TBD	TBD	230	330	350	490	μA
		125	TBD	TBD	570	680	810	1250	μA
VLPS and LPUART TX/RX	<ul style="list-style-type: none"> <li>• Clock source: SIRC</li> <li>• Transmitting or receiving continuously using DMA</li> <li>• Baudrate: 19.2 kbps</li> </ul>	25	TBD	TBD	230	230	250	250	μA
		85	TBD	TBD	320	400	410	490	μA
		105	TBD	TBD	490	550	600	850	μA
		125	TBD	TBD	890	1070	1250	1960	μA
VLPS and LPUART wake-up	<ul style="list-style-type: none"> <li>• Clock source: SIRC</li> <li>• Wake-up address feature enabled</li> <li>• Baudrate: 19.2 kbps</li> </ul>	25	TBD	TBD	100	100	110	110	μA
		85	TBD	TBD	170	240	280	350	μA
		105	TBD	TBD	260	400	480	600	μA
		125	TBD	TBD	530	580	1000	1280	μA
VLPS and LPI2C master	<ul style="list-style-type: none"> <li>• Clock Source: SIRC</li> <li>• Transmit/receive using DMA</li> <li>• Baudrate: 100 kHz</li> </ul>	25	TBD	TBD	670	690	820	900	μA
		85	TBD	TBD	880	960	1220	1370	μA
		105	TBD	TBD	1080	1250	1660	2060	μA
		125	TBD	TBD	1970	1980	2860	3690	μA
VLPS and LPI2C slave wake-up	<ul style="list-style-type: none"> <li>• Clock source: SIRC</li> <li>• Wake-up address feature enabled</li> <li>• Baudrate: 100 kHz</li> </ul>	25	TBD	TBD	250	250	270	280	μA
		85	TBD	TBD	340	340	410	510	μA
		105	TBD	TBD	430	430	610	810	μA
		125	TBD	TBD	740	760	1170	1540	μA
VLPS and LPSPI master	<ul style="list-style-type: none"> <li>• Clock source: SIRC</li> <li>• Transmit/receive using DMA</li> <li>• Baudrate: 500 kHz</li> </ul>	25	TBD	TBD	2.99	3.19	3.75	4.11	mA
		85	TBD	TBD	3.26	3.7	4.35	4.93	mA
		105	TBD	TBD	3.5	4.2	4.93	5.74	mA
		125	TBD	TBD	3.93	4.63	5.97	7.38	mA
VLPS and LPIT	<ul style="list-style-type: none"> <li>• Clock source: SIRC</li> <li>• 1 channel enable</li> <li>• Mode: 32-bit periodic counter</li> </ul>	25	TBD	TBD	100	100	120	130	μA
		85	TBD	TBD	190	250	260	320	μA
		105	TBD	TBD	310	410	440	570	μA
		125	TBD	TBD	640	750	910	1280	μA

## I/O parameters

- Several I/O have both high drive and normal drive capability selected by the associated Portx\_PCRn[DSE] control bit. All other GPIOs are normal drive only. For details see IO Signal Description Input Multiplexing sheet(s) attached with the *Reference Manual*.
- When using ENET and SAI on S32K148, the overall device limits associated with high drive pin configurations must be respected i.e. On 144-pin LQFP the general purpose pins: PTA10, PTD0, and PTE4 must be set to low drive.
- Measured at input  $V = V_{SS}$
- Measured at input  $V = V_{DD}$

## 5.4 DC electrical specifications at 5.0 V Range

**Table 12. DC electrical specifications at 5.0 V Range**

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
$V_{DD}$	I/O Supply Voltage	4	—	5.5	V	
$V_{ih}$	Input Buffer High Voltage	$0.65 \times V_{DD}$	—	$V_{DD} + 0.3$	V	1
$V_{il}$	Input Buffer Low Voltage	$V_{SS} - 0.3$	—	$0.35 \times V_{DD}$	V	2
$V_{hys}$	Input Buffer Hysteresis	$0.06 \times V_{DD}$	—	—	V	
$I_{ohGPIO}$ $I_{ohGPIO-HD\_DSE\_0}$	I/O current source capability measured when pad $V_{oh} = (V_{DD} - 0.8 \text{ V})$	5	—	—	mA	
$I_{olGPIO}$ $I_{olGPIO-HD\_DSE\_0}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	5	—	—	mA	
$I_{ohGPIO-HD\_DSE\_1}$	I/O current source capability measured when pad $V_{oh} = V_{DD} - 0.8 \text{ V}$	20	—	—	mA	3
$I_{olGPIO-HD\_DSE\_1}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	20	—	—	mA	3
$I_{ohGPIO-FAST\_DSE\_0}$	I/O current sink capability measured when pad $V_{oh} = V_{DD} - 0.8 \text{ V}$	14.0	—	—	mA	4
$I_{olGPIO-FAST\_DSE\_0}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	14.5	—	—	mA	4
$I_{ohGPIO-FAST\_DSE\_1}$	I/O current sink capability measured when pad $V_{oh} = V_{DD} - 0.8 \text{ V}$	21	—	—	mA	4
$I_{olGPIO-FAST\_DSE\_1}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	20.5	—	—	mA	4
IOHT	Output high current total for all ports	—	—	100	mA	
IIN	Input leakage current (per pin) for full temperature range at $V_{DD} = 5.5 \text{ V}$					5
	All pins other than high drive port pins		0.005	0.5	$\mu\text{A}$	
	High drive port pins		0.010	0.5	$\mu\text{A}$	
$R_{PU}$	Internal pullup resistors	20		50	$k\Omega$	6
$R_{PD}$	Internal pulldown resistors	20		50	$k\Omega$	7

- For reset pads, same  $V_{ih}$  levels are applicable
- For reset pads, same  $V_{il}$  levels are applicable
- The strong pad I/O pin is capable of switching a 50 pF load up to 40 MHz.
- For reference only. Run simulations with the IBIS model and custom board for accurate results.

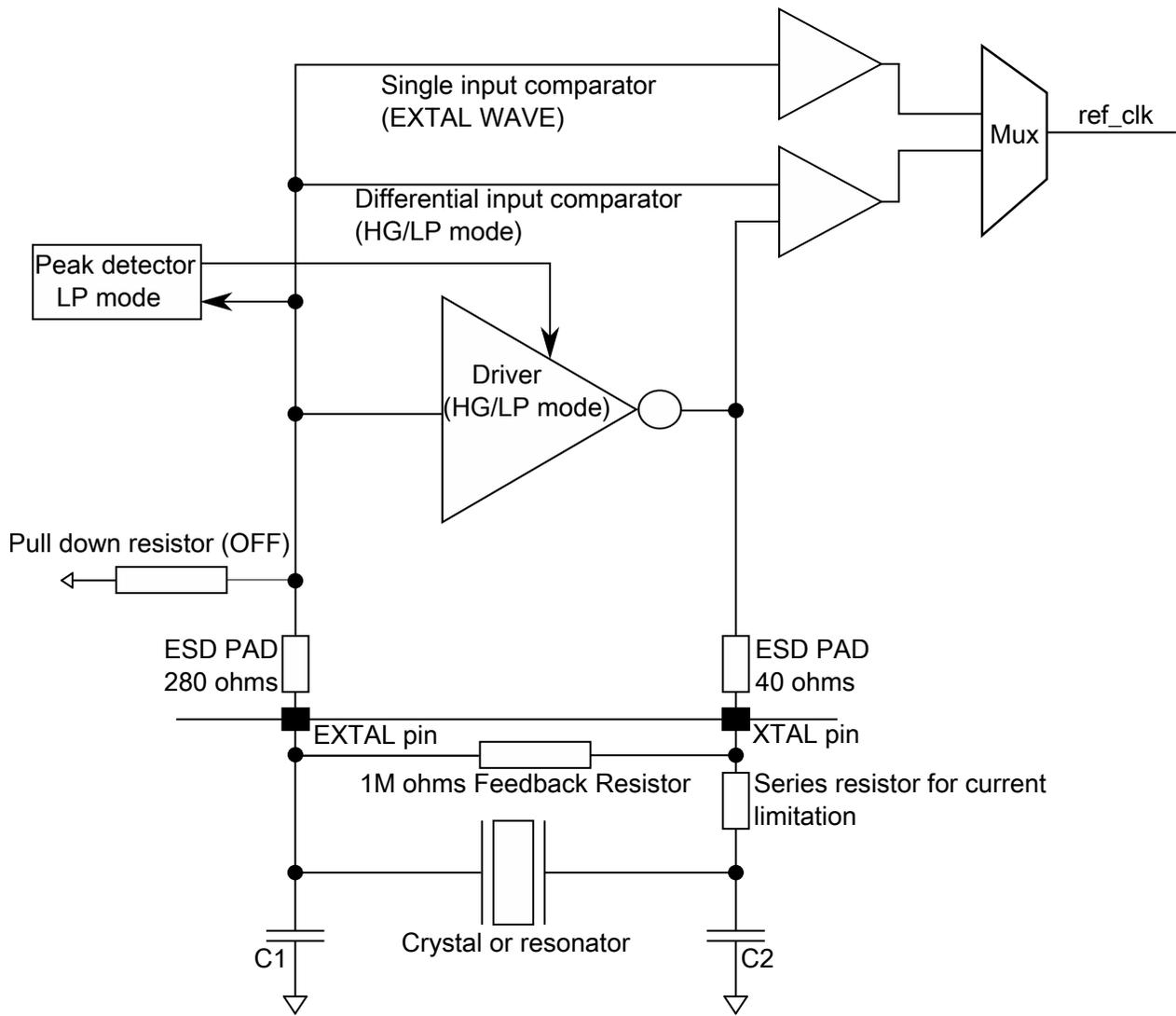


Figure 8. Oscillator connections scheme

Table 17. External System Oscillator electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
g <sub>mXOSC</sub>	Crystal oscillator transconductance					
	SCG_SOSCCFG[RANGE]=2'b10 for 4-8 MHz	2.2	—	13.7	mA/V	
	SCG_SOSCCFG[RANGE]=2'b11 for 8-40 MHz	16	—	47	mA/V	
V <sub>IL</sub>	Input low voltage — EXTAL pin in external clock mode	V <sub>SS</sub>	—	1.15	V	
V <sub>IH</sub>	Input high voltage — EXTAL pin in external clock mode	0.7 * V <sub>DD</sub>	—	V <sub>DD</sub>	V	
C <sub>1</sub>	EXTAL load capacitance	—	—	—		1
C <sub>2</sub>	XTAL load capacitance	—	—	—		1
R <sub>F</sub>	Feedback resistor					2
	Low-gain mode (HGO=0)	—	—	—	MΩ	

Table continues on the next page...

## 6.2.3 System Clock Generation (SCG) specifications

### 6.2.3.1 Fast internal RC Oscillator (FIRC) electrical specifications

Table 19. Fast internal RC Oscillator electrical specifications

Symbol	Parameter <sup>1</sup>	Value			Unit
		Min.	Typ.	Max.	
$F_{\text{FIRC}}$	FIRC target frequency	—	48	—	MHz
$\Delta F$	Frequency deviation across process, voltage, and temperature < 105°C	—	±0.5	±1	% $F_{\text{FIRC}}$
$\Delta F_{125}$	Frequency deviation across process, voltage, and temperature < 125°C	—	±0.5	±1.1	% $F_{\text{FIRC}}$
$T_{\text{Startup}}$	Startup time		3.4	5	$\mu\text{s}^2$
$T_{\text{JIT}}^3$	Cycle-to-Cycle jitter	—	300	500	ps
$T_{\text{JIT}}^3$	Long term jitter over 1000 cycles	—	0.04	0.1	% $F_{\text{FIRC}}$

1. With FIRC regulator enable
2. Startup time is defined as the time between clock enablement and clock availability for system use.
3. FIRC as system clock

#### NOTE

Fast internal RC Oscillator is compliant with CAN and LIN standards.

### 6.2.3.2 Slow internal RC oscillator (SIRC) electrical specifications

Table 20. Slow internal RC oscillator (SIRC) electrical specifications

Symbol	Parameter	Value			Unit
		Min.	Typ.	Max.	
$F_{\text{SIRC}}$	SIRC target frequency	—	8	—	MHz
$\Delta F$	Frequency deviation across process, voltage, and temperature < 105°C	—	—	±3	% $F_{\text{SIRC}}$
$\Delta F_{125}$	Frequency deviation across process, voltage, and temperature < 125°C	—	—	±3.3	% $F_{\text{SIRC}}$
$T_{\text{Startup}}$	Startup time	—	9	12.5	$\mu\text{s}^1$

1. Startup time is defined as the time between clock enablement and clock availability for system use.

## 6.2.4 Low Power Oscillator (LPO) electrical specifications

Table 21. Low Power Oscillator (LPO) electrical specifications

Symbol	Parameter	Min.	Typ.	Max.	Unit
F <sub>LPO</sub>	Internal low power oscillator frequency	113	128	139	kHz
T <sub>startup</sub>	Startup Time	—	—	20	μs

## 6.2.5 SPLL electrical specifications

Table 22. SPLL electrical specifications

Symbol	Parameter	Min.	Typ.	Max.	Unit
F <sub>SPLL_REF</sub> <sup>1</sup>	PLL Reference Frequency Range	8	—	16	MHz
F <sub>SPLL_Input</sub> <sup>2</sup>	PLL Input Frequency	8	—	40	MHz
F <sub>VCO_CLK</sub>	VCO output frequency	180	—	320	MHz
F <sub>SPLL_CLK</sub>	PLL output frequency	90	—	160	MHz
J <sub>CYC_SPLL</sub>	PLL Period Jitter (RMS) <sup>3</sup>				
	at F <sub>VCO_CLK</sub> 180 MHz	—	120	—	ps
	at F <sub>VCO_CLK</sub> 320 MHz	—	75	—	ps
J <sub>ACC_SPLL</sub>	PLL accumulated jitter over 1μs (RMS) <sup>3</sup>				
	at F <sub>VCO_CLK</sub> 180 MHz	—	1350	—	ps
	at F <sub>VCO_CLK</sub> 320 MHz	—	600	—	ps
D <sub>UNL</sub>	Lock exit frequency tolerance	± 4.47	—	± 5.97	%
T <sub>SPLL_LOCK</sub>	Lock detector detection time <sup>4</sup>	—	—	150 × 10 <sup>-6</sup> + 1075(1/F <sub>SPLL_REF</sub> )	s

1. F<sub>SPLL\_REF</sub> is PLL reference frequency range after the PREDIV. For PREDIV and MULT settings refer SCG\_SPLL\_CFG register of Reference Manual.
2. F<sub>SPLL\_Input</sub> is PLL input frequency range before the PREDIV must be limited to the range 8 MHz to 40 MHz. This input source could be derived from a crystal oscillator or some other external square wave clock source using OSC bypass mode. For external clock source settings refer SCG\_SOSCCFG register of Reference Manual.
3. This specification was obtained using a NXP developed PCB. PLL jitter is dependent on the noise characteristics of each PCB and results will vary
4. Lock detector detection time is defined as the time between PLL enablement and clock availability for system use.

## 6.3 Memory and memory interfaces

### 6.3.1 Flash memory module (FTFC) electrical specifications

This section describes the electrical characteristics of the flash memory module.

## 6.3.1.1 Flash timing specifications — commands

Table 23. Flash command timing specifications for S32K14x

Symbol	Description <sup>1</sup>		S32K142		S32K144		S32K146		S32K148		Unit	Notes
			Typ	Max	Typ	Max	Typ	Max	Typ	Max		
$t_{rd1blk}$	Read 1 Block execution time	32 KB flash	—	—	—	—	—	—	—	—	ms	
		64 KB flash	—	0.5	—	0.5	—	0.5	—	—		
		128 KB flash	—	—	—	—	—	—	—	—		
		256 KB flash	—	2	—	—	—	—	—	—		
		512 KB flash	—	—	—	1.8	—	2	—	2		
$t_{rd1sec}$	Read 1 Section execution time	2 KB flash	—	75	—	75	—	75	—	75	$\mu$ s	
		4 KB flash	—	100	—	100	—	100	—	100		
$t_{pgmchk}$	Program Check execution time	—	—	95	—	95	—	95	—	100	$\mu$ s	
$t_{pgm8}$	Program Phrase execution time	—	90	225	90	225	90	225	90	225	$\mu$ s	
$t_{ersblk}$	Erase Flash Block execution time	32 KB flash	—	—	—	—	—	—	—	—	ms	2
		64 KB flash	30	550	30	550	30	550	—	—		
		128 KB flash	—	—	—	—	—	—	—	—		
		256 KB flash	250	2125	—	—	—	—	—	—		
		512 KB flash	—	—	250	4250	250	4250	250	4250		
$t_{ersscr}$	Erase Flash Sector execution time	—	12	130	12	130	12	130	12	130	ms	2
$t_{pgmsec1k}$	Program Section execution time (1KB flash)	—	5	—	5	—	5	—	5	—	ms	
$t_{rd1all}$	Read 1s All Block execution time	—	—	2.8	—	2.3	—	5.2	—	8.2	ms	
$t_{rdonce}$	Read Once execution time	—	—	30	—	30	—	30	—	30	$\mu$ s	
$t_{pgmonce}$	Program Once execution time	—	90	—	90	—	90	—	90	—	$\mu$ s	
$t_{ersall}$	Erase All Blocks execution time	—	250	2800	400	4900	700	10000	1400	17000	ms	2
$t_{vfykey}$	Verify Backdoor Access Key execution time	—	—	35	—	35	—	35	—	35	$\mu$ s	
$t_{ersallu}$	Erase All Blocks Unsecure execution time	—	250	2800	400	4900	700	10000	1400	17000	ms	2
$t_{pgmpart}$	Program Partition for EEPROM backup execution time	32 KB EEPROM backup	70	—	70	—	70	—	—	—	ms	3
		64 KB EEPROM backup	71	—	71	—	71	—	150	—		

Table continues on the next page...

Table 26. QuadSPI electrical specifications

FLASH PORT	Sym	Unit	FLASH A											FLASH B				
			RUN <sup>1</sup>						HSRUN <sup>1</sup>					RUN/HSRUN <sup>2</sup>				
			SDR						SDR					SDR		DDR <sup>3</sup>		
			Internal Sampling		Internal DQS				Internal Sampling		Internal DQS			Internal Sampling		External DQS		
			N1		PAD Loopback		Internal Loopback		N1		PAD Loopback		Internal Loopback		N1		External DQS	
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max
Register Settings																		
MCR[DDR_EN]		-	0	0	0	0	0	0	0	0	0	0	0	0	0	1		
MCR[DQS_EN]		-	0	1	1	0	1	1	0	1	1	0	1	0	1			
MCR[SCLKCFG[0]]		-	-	1	0	-	1	0	-	1	0	-	-	-	-	-	-	-
MCR[SCLKCFG[1]]		-	-	1	0	-	1	0	-	1	0	-	-	-	-	-	-	-
MCR[SCLKCFG[2]]		-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	0
MCR[SCLKCFG[3]]		-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-	0
MCR[SCLKCFG[5]]		-	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1	
SMPR[FSPHS]		-	0	1	0	0	1	0	0	1	0	0	0	0	0	0	0	0
SMPR[FSDLY]		-	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
SOCCR [SOCCFG[7:0]]			-	0	23	-	0	30	-	0	30	-	-	-	-	-	-	-
SOCCR[SOCCFG[15:8]]		-	-	-	-	-	-	-	-	-	-	-	-	-	-	30		
FLSHCR[TDH]		-	0x00	0x00	0x00	0x00	0x00	0x00	0x00	0x00	0x00	0x00	0x00	0x00	0x00	0x01		
Timing Parameters																		
SCK Clock Frequency	f <sub>SCK</sub>	MHz	-	38	-	64	-	48	-	40	-	80	-	50	-	20	-	20 <sup>4</sup>
SCK Clock Period	t <sub>SCK</sub>	ns	1/SCK	-	1/SCK	-	1/SCK	-	1/SCK	-	1/SCK	-	1/SCK	-	50.0	-	50.0 <sup>4</sup>	-

Table continues on the next page...

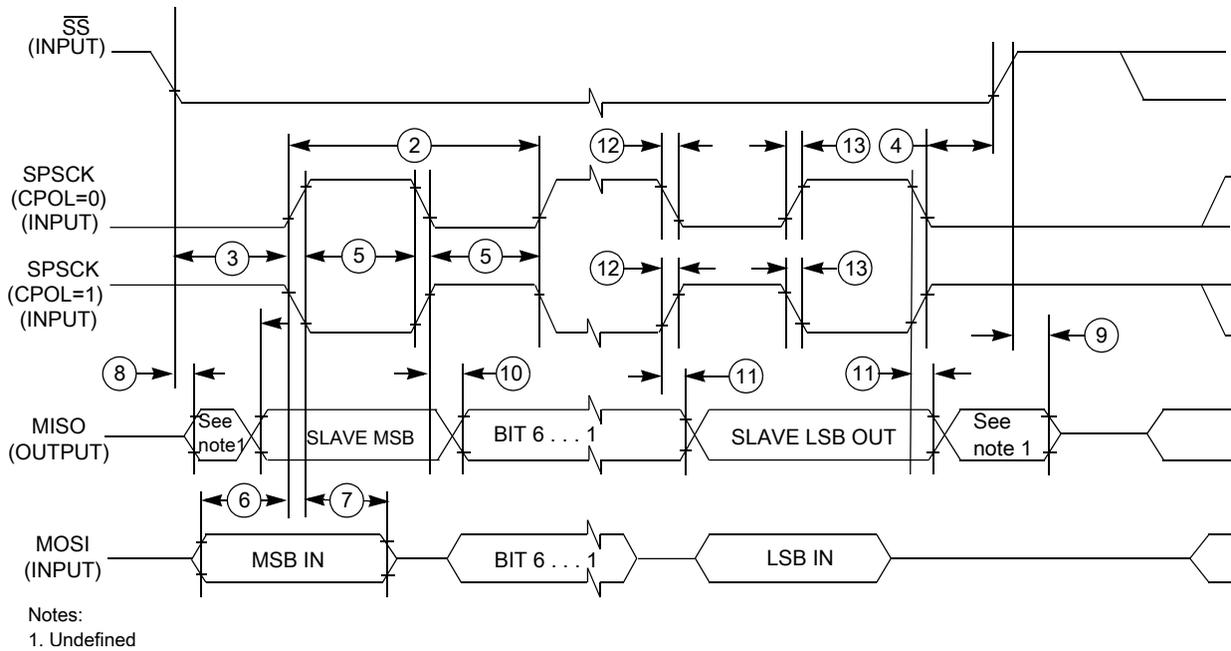


Figure 20. LPSPI slave mode timing (CPHA = 0)

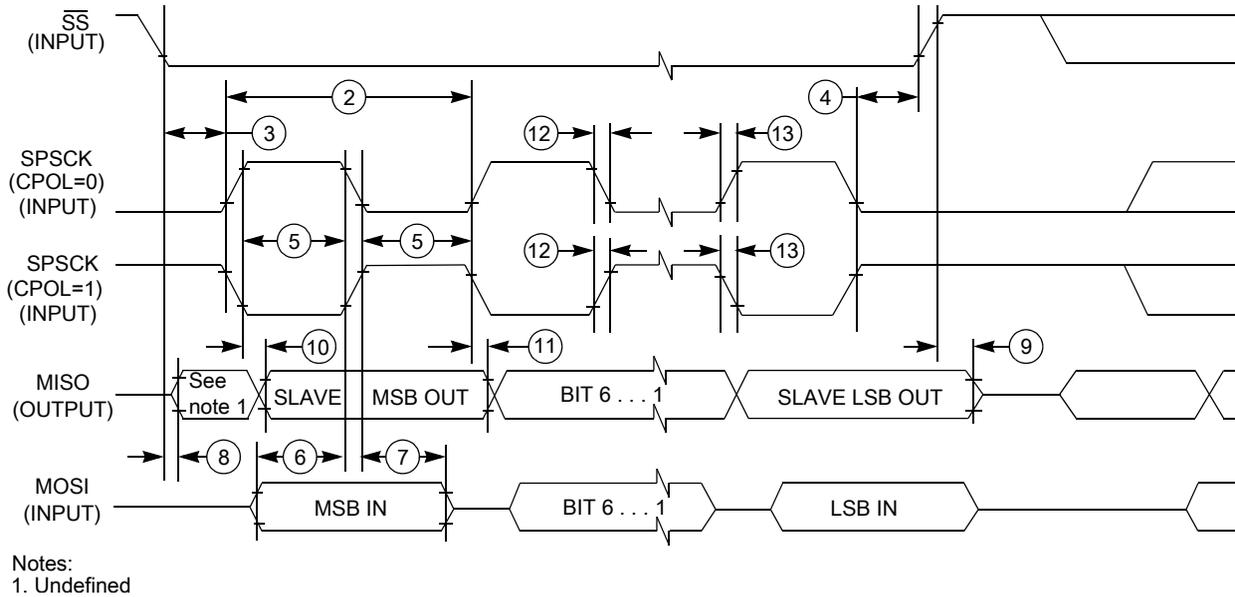


Figure 21. LPSPI slave mode timing (CPHA = 1)

### 6.5.3 LPI2C electrical specifications

See [General AC specifications](#) for LPI2C specifications.

For supported baud rate see section 'Chip-specific LPI2C information' of the *Reference Manual*.

## 6.5.4 FlexCAN electrical specifications

For supported baud rate, see section 'Protocol timing' of the *Reference Manual*.

## 6.5.5 SAI electrical specifications

The following table describes the SAI electrical characteristics.

- Measurements are with maximum output load of 50 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN ), the interface should be OFF.

**Table 33. Master mode timing specifications**

Symbol	Description	Min.	Max.	Unit
—	Operating voltage	2.97	3.6	V
S1	SAI_MCLK cycle time	40	—	ns
S2	SAI_MCLK pulse width high/low	45%	55%	MCLK period
S3	SAI_BCLK cycle time	80	—	ns
S4	SAI_BCLK pulse width high/low	45%	55%	BCLK period
S5	SAI_RXD input setup before SAI_BCLK	28	—	ns
S6	SAI_RXD input hold after SAI_BCLK	0	—	ns
S7	SAI_BCLK to SAI_TXD output valid	—	8	ns
S8	SAI_BCLK to SAI_TXD output invalid	-2	—	ns
S9	SAI_FS input setup before SAI_BCLK	28	—	ns
S10	SAI_FS input hold after SAI_BCLK	0	—	ns
S11	SAI_BCLK to SAI_FS output valid	—	8	ns
S12	SAI_BCLK to SAI_FS output invalid	-2	—	ns

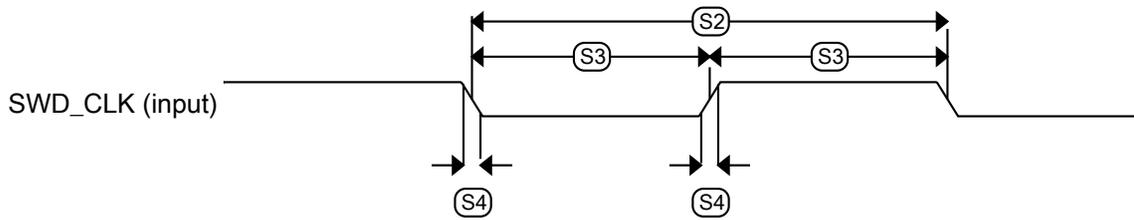


Figure 29. Serial wire clock input timing

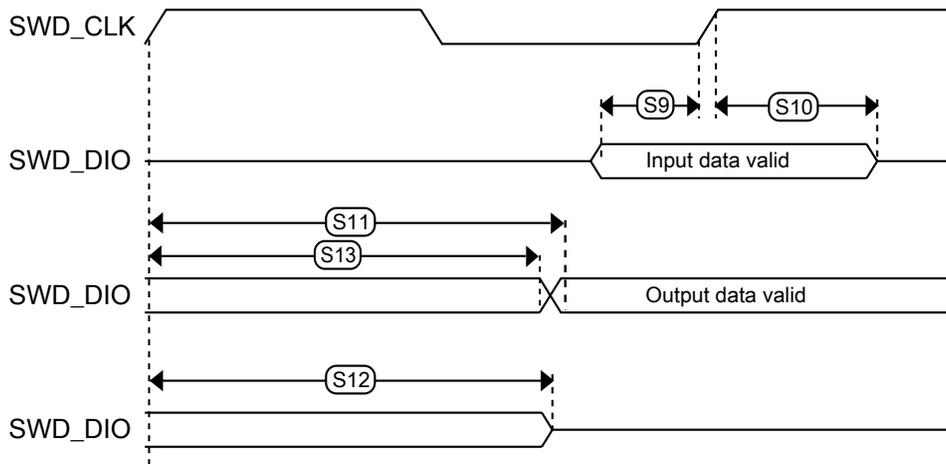


Figure 30. Serial wire data timing

### 6.6.2 Trace electrical specifications

The following table describes the Trace electrical characteristics.

- Measurements are with maximum output load of 50 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN ), the interface should be OFF.

Table 39. Trace specifications

	Symbol	Description	RUN Mode			HSRUN Mode		VLPR Mode	Unit
			80	48	40	112	80		
—	Fsys	System frequency	80	48	40	112	80	4	MHz

Table continues on the next page...

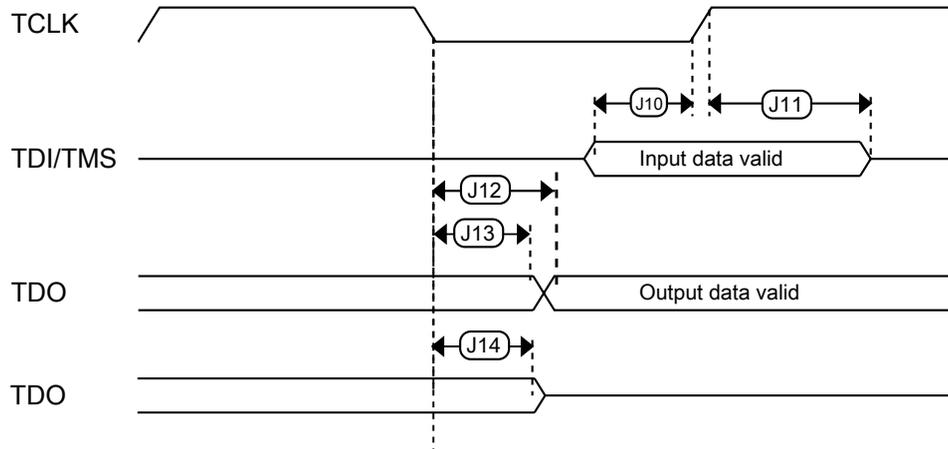


Figure 34. Test Access Port timing

## 7 Thermal attributes

### 7.1 Description

The tables in the following sections describe the thermal characteristics of the device.

#### NOTE

Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting side (board) temperature, ambient temperature, air flow, power dissipation or other components on the board, and board thermal resistance.

### 7.2 Thermal characteristics

**Table 41. Thermal characteristics for 32-pin QFN and 48/64/100/144/176-pin LQFP package**

Rating	Conditions	Symbol	Package	Values						Unit
				S32K116	S32K118	S32K142	S32K144	S32K146	S32K148	
Thermal resistance, Junction to Ambient (Natural Convection) <sup>1, 2</sup>	Single layer board (1s)	$R_{\theta JA}$	32	93	NA	NA	NA	NA	NA	°C/W
			48	79	71	NA	NA	NA	NA	
			64	NA	62	61	61	59	NA	
			100	NA	NA	53	52	51	NA	
			144	NA	NA	NA	NA	51	44	
			176	NA	NA	NA	NA	NA	42	
Thermal resistance, Junction to Ambient (Natural Convection) <sup>1</sup>	Two layer board (1s1p)	$R_{\theta JA}$	32	50	NA	NA	NA	NA	NA	°C/W
			48	58	50	NA	NA	NA	NA	
			64	NA	46	45	45	44	NA	
			100	NA	NA	42	42	40	NA	
			144	NA	NA	NA	NA	44	37	
			176	NA	NA	NA	NA	NA	36	
Thermal resistance, Junction to Ambient (Natural Convection) <sup>1, 2</sup>	Four layer board (2s2p)	$R_{\theta JA}$	32	32	NA	NA	NA	NA	NA	°C/W
			48	55	47	NA	NA	NA	NA	
			64	NA	44	43	43	41	NA	
			100	NA	NA	40	40	39	NA	
			144	NA	NA	NA	NA	42	36	
			176	NA	NA	NA	NA	NA	35	
Thermal resistance, Junction to Ambient (@200 ft/min) <sup>1, 3</sup>	Single layer board (1s)	$R_{\theta JMA}$	32	77	NA	NA	NA	NA	NA	°C/W
			48	66	58	NA	NA	NA	NA	
			64	NA	50	49	49	48	NA	
			100	NA	NA	43	42	41	NA	
			144	NA	NA	NA	NA	42	36	
			176	NA	NA	NA	NA	NA	34	
Thermal resistance, Junction to Ambient (@200 ft/min) <sup>1</sup>	Two layer board (1s1p)	$R_{\theta JMA}$	32	43	NA	NA	NA	NA	NA	°C/W
			48	51	43	NA	NA	NA	NA	
			64	NA	39	38	38	37	NA	
			100	NA	NA	35	35	34	NA	

Table continues on the next page...

**Table 41. Thermal characteristics for 32-pin QFN and 48/64/100/144/176-pin LQFP package (continued)**

Rating	Conditions	Symbol	Package	Values						Unit	
				S32K116	S32K118	S32K142	S32K144	S32K146	S32K148		
			144	NA	NA	NA	NA	37	31		
			176	NA	NA	NA	NA	NA	30		
Thermal resistance, Junction to Ambient (@200 ft/min) <sup>1, 3</sup>	Four layer board (2s2p)	$R_{\theta JMA}$	32	26	NA	NA	NA	NA	NA		
			48	48	41	NA	NA	NA	NA		
			64	NA	37	36	36	35	NA		
			100	NA	NA	34	34	33	NA		
			144	NA	NA	NA	NA	36	30		
			176	NA	NA	NA	NA	NA	29		
Thermal resistance, Junction to Board <sup>4</sup>	—	$R_{\theta JB}$	32	11	NA	NA	NA	NA	NA		
			48	33	24	NA	NA	NA	NA		
			64	NA	26	25	25	23	NA		
			100	NA	NA	25	25	24	NA		
			144	NA	NA	NA	NA	30	24		
			176	NA	NA	NA	NA	NA	24		
Thermal resistance, Junction to Case <sup>5</sup>	—	$R_{\theta JC}$	32	NA	NA	NA	NA	NA	NA		
			48	23	19	NA	NA	NA	NA		
			64	NA	14	13	12	11	NA		
			100	NA	NA	13	12	11	NA		
			144	NA	NA	NA	NA	12	9		
			176	NA	NA	NA	NA	NA	9		
Thermal resistance, Junction to Case (Bottom) <sup>6</sup>	—	$R_{\theta JCBottom}$	32	1	NA						
			48	NA							
			64	NA							
			100	NA							
			144	NA							
			176	NA							

Table continues on the next page...

### 7.3 General notes for specifications at maximum junction temperature

An estimation of the chip junction temperature,  $T_J$ , can be obtained from this equation:

$$T_J = T_A + (R_{\theta JA} \times P_D)$$

where:

- $T_A$  = ambient temperature for the package ( $^{\circ}\text{C}$ )
- $R_{\theta JA}$  = junction to ambient thermal resistance ( $^{\circ}\text{C}/\text{W}$ )
- $P_D$  = power dissipation in the package ( $\text{W}$ )

The junction to ambient thermal resistance is an industry standard value that provides a quick and easy estimation of thermal performance. Unfortunately, there are two values in common usage: the value determined on a single layer board and the value obtained on a board with two planes. For packages such as the PBGA, these values can be different by a factor of two. Which value is closer to the application depends on the power dissipated by other components on the board. The value obtained on a single layer board is appropriate for the tightly packed printed circuit board. The value obtained on the board with the internal planes is usually appropriate if the board has low power dissipation and the components are well separated.

When a heat sink is used, the thermal resistance is expressed in the following equation as the sum of a junction-to-case thermal resistance and a case-to-ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$

where:

- $R_{\theta JA}$  = junction to ambient thermal resistance ( $^{\circ}\text{C}/\text{W}$ )
- $R_{\theta JC}$  = junction to case thermal resistance ( $^{\circ}\text{C}/\text{W}$ )
- $R_{\theta CA}$  = case to ambient thermal resistance ( $^{\circ}\text{C}/\text{W}$ )

$R_{\theta JC}$  is device related and cannot be influenced by the user. The user controls the thermal environment to change the case to ambient thermal resistance,  $R_{\theta CA}$ . For instance, the user can change the size of the heat sink, the air flow around the device, the interface material, the mounting arrangement on printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device.

Table 43. Revision History (continued)

Rev. No.	Date	Substantial Changes
		<ul style="list-style-type: none"> <li>• Updated values for <math>V_{REFH}</math> and <math>V_{REFL}</math> to add reference to the section "voltage and current operating requirements" for Min and Max values</li> <li>• Updated footnote to Typ.</li> <li>• Removed footnote from RAS Analog source resistance</li> <li>• Updated figure: ADC input impedance equivalency diagram</li> <li>• In table: <a href="#">12-bit ADC characteristics (2.7 V to 3 V)</a> (<math>V_{REFH} = V_{DDA}</math>, <math>V_{REFL} = V_{SS}</math>) <ul style="list-style-type: none"> <li>• Removed rows for <math>V_{TEMP\_S}</math> and <math>V_{TEMP25}</math></li> <li>• Updated footnote to Typ.</li> </ul> </li> <li>• In table: <a href="#">12-bit ADC characteristics (3 V to 5.5 V)</a> (<math>V_{REFH} = V_{DDA}</math>, <math>V_{REFL} = V_{SS}</math>) <ul style="list-style-type: none"> <li>• Removed rows for <math>V_{TEMP\_S}</math> and <math>V_{TEMP25}</math></li> <li>• Removed number for TUE</li> <li>• Updated footnote to Typ.</li> </ul> </li> <li>• In table: <a href="#">Comparator with 8-bit DAC electrical specifications</a> <ul style="list-style-type: none"> <li>• Updated Typ. of <math>I_{DDL5}</math> Supply current, Low-speed mode</li> <li>• Updated Typ. of <math>t_{DL5B}</math> Propagation delay, Low-speed mode</li> <li>• Updated Typ. of <math>t_{DH5S}</math> Propagation delay, High-speed mode</li> <li>• Updated <math>t_{DL5S}</math> Propagation delay</li> <li>• Added row for <math>t_{DDAC}</math> Initialization and switching settling time</li> <li>• Updated footnote</li> </ul> </li> <li>• Updated section <a href="#">LPSPI electrical specifications</a></li> <li>• Added section: <a href="#">SAI electrical specifications</a></li> <li>• Updated section: <a href="#">Ethernet AC specifications</a></li> <li>• Added section: <a href="#">Clockout frequency</a></li> <li>• Added section: <a href="#">Trace electrical specifications</a></li> <li>• Updated table: <a href="#">Table 41</a> : Updated numbers for S32K142 and S32K148</li> <li>• Updated table: <a href="#">Table 42</a> : Updated numbers for S32K148</li> <li>• Updated Document number for 32-pin QFN in topic <a href="#">Obtaining package dimensions</a></li> </ul>
3	14 March 2017	<ul style="list-style-type: none"> <li>• In <a href="#">Table 2</a> <ul style="list-style-type: none"> <li>• Updated min. value of <math>V_{DD\_OFF}</math></li> <li>• Added parameter <math>I_{INJSUM\_AF}</math></li> </ul> </li> <li>• Updated <a href="#">Power mode transition operating behaviors</a></li> <li>• Updated <a href="#">Power consumption</a></li> <li>• Updated footnote to <math>T_{SPLL\_LOCK}</math> in <a href="#">SPLL electrical specifications</a></li> <li>• In <a href="#">12-bit ADC electrical characteristics</a> <ul style="list-style-type: none"> <li>• Updated table: <a href="#">12-bit ADC characteristics (2.7 V to 3 V)</a> (<math>V_{REFH} = V_{DDA}</math>, <math>V_{REFL} = V_{SS}</math>) <ul style="list-style-type: none"> <li>• Added typ. value to <math>I_{DDA\_ADC}</math>, TUE, DNL, and INL</li> <li>• Added min. value to SMPLTS</li> <li>• Removed footnote 'All the parameters in this table ...'</li> </ul> </li> <li>• Updated table: <a href="#">12-bit ADC characteristics (3 V to 5.5 V)</a> (<math>V_{REFH} = V_{DDA}</math>, <math>V_{REFL} = V_{SS}</math>) <ul style="list-style-type: none"> <li>• Added typ. value to <math>I_{DDA\_ADC}</math></li> <li>• Removed footnote 'All the parameters in this table ...'</li> </ul> </li> </ul> </li> <li>• In <a href="#">Flash timing specifications — commands</a> updated Max. value of <math>t_{Vfykey}</math> to 33 <math>\mu</math>s</li> </ul>
4	02 June 2017	<ul style="list-style-type: none"> <li>• In section: <a href="#">Block diagram</a>, added block diagram for S32K11x series.</li> <li>• Updated figure: <a href="#">S32K1xx product series comparison</a>.</li> <li>• In section: <a href="#">Selecting orderable part number</a>, added reference to attachment <a href="#">S32K_Part_Numbers.xlsx</a>.</li> <li>• In section: <a href="#">Ordering information</a> <ul style="list-style-type: none"> <li>• Updated figure: Ordering information.</li> </ul> </li> <li>• In <a href="#">Table 1</a>,</li> </ul>

Table continues on the next page...

Table 43. Revision History (continued)

Rev. No.	Date	Substantial Changes
		<ul style="list-style-type: none"> <li>• Updated note 'All the limits defined ...'</li> <li>• Updated parameter 'I<sub>INJPAD_DC_ABS</sub>', 'V<sub>IN_DC</sub>', I<sub>INJSUM_DC_ABS</sub>.</li> <li>• In <a href="#">Table 2</a>, <ul style="list-style-type: none"> <li>• Updated parameter I<sub>INJPAD_DC_OP</sub> and I<sub>INJSUM_DC_OP</sub>.</li> </ul> </li> <li>• In <a href="#">Table 5</a>, updated TBDs for V<sub>LVR_HYST</sub>, V<sub>LVD_HYST</sub>, and V<sub>LVW_HYST</sub></li> <li>• In <a href="#">Power mode transition operating behaviors</a>, <ul style="list-style-type: none"> <li>• Added VLPR → VLPS</li> <li>• Added VLPS → VLPR</li> <li>• Updated TBDs for VLPS → Asynchronous DMA Wakeup, STOP1 → Asynchronous DMA Wakeup, and STOP2 → Asynchronous DMA Wakeup</li> </ul> </li> <li>• In <a href="#">Table 7</a>, updated the specifications for S32K144.</li> <li>• Updated the attachment <i>S32K1xx_Power_Modes_Configuration.xlsx</i>.</li> <li>• In <a href="#">Table 15</a>, removed C<sub>IN_A</sub>.</li> <li>• In <a href="#">Table 17</a>, <ul style="list-style-type: none"> <li>• Updated specificatins for g<sub>mXOSC</sub>.</li> <li>• Removed I<sub>DDOSC</sub></li> </ul> </li> <li>• In <a href="#">Table 19</a>, <ul style="list-style-type: none"> <li>• Added parameter ΔF125.</li> <li>• Removed I<sub>DDFIRC</sub></li> </ul> </li> <li>• In <a href="#">Table 20</a>, <ul style="list-style-type: none"> <li>• Added parameter ΔF125.</li> <li>• Removed I<sub>DDSIRC</sub></li> </ul> </li> <li>• In <a href="#">Table 21</a>, removed I<sub>LPO</sub></li> <li>• Updated section: <a href="#">Flash memory module (FTFC) electrical specifications</a></li> <li>• In section: <a href="#">12-bit ADC operating conditions</a>, <ul style="list-style-type: none"> <li>• Updated TBDs for I<sub>DDA_ADC</sub> and TUE in <a href="#">Table 28</a></li> <li>• Updated TBDs for I<sub>DDA_ADC</sub> and TUE in <a href="#">Table 29</a></li> </ul> </li> <li>• In section: <a href="#">QuadSPI AC specifications</a>, updated figure 'QuadSPI output timing (HyperRAM mode) diagram'.</li> <li>• In section: <a href="#">12-bit ADC operating conditions</a>, updated <a href="#">Table 27</a>.</li> <li>• In section: <a href="#">CMP with 8-bit DAC electrical specifications</a>, added note 'For comparator IN signals adjacent ...'</li> <li>• In table: <a href="#">Table 32</a>, minor update in footnote 6.</li> <li>• In table: <a href="#">Table 41</a>, updated specifications for S32K146.</li> </ul>
5	06 Dec 2017	<ul style="list-style-type: none"> <li>• Removed S32K148 from 'Caution'</li> <li>• Updated figure: <a href="#">S32K1xx product series comparison</a> for <ul style="list-style-type: none"> <li>• 'EEPROM emulated by FlexRAM' of S32K148 (Added content to footnote)</li> <li>• Added support for LIN protocol version 2.2 A</li> </ul> </li> <li>• In <a href="#">Absolute maximum ratings</a> : <ul style="list-style-type: none"> <li>• Added note 'Unless otherwise ...'</li> <li>• Added parameter 'Added note 'T<sub>ramp_MCU</sub>'</li> <li>• Updated footnote for 'T<sub>ramp</sub>'</li> </ul> </li> <li>• In <a href="#">Voltage and current operating requirements</a> : <ul style="list-style-type: none"> <li>• Added footnote 'V<sub>DD</sub> and V<sub>DDA</sub> must be shorted ...' against parameter 'V<sub>DD</sub>-V<sub>DDA</sub>'</li> <li>• Updated footnote 'V<sub>DD</sub> and V<sub>DDA</sub> must be shorted ...'</li> </ul> </li> <li>• In <a href="#">Power and ground pins</a> <ul style="list-style-type: none"> <li>• Added diagrams for 32-QFN and 48-LQFP and footnote below the diagrams.</li> <li>• Updated footnote 'V<sub>DD</sub> and V<sub>DDA</sub> must be shorted ...'</li> </ul> </li> <li>• In <a href="#">Power mode transition operating behaviors</a> :</li> </ul>

Table continues on the next page...